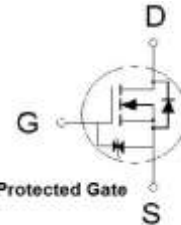




PRODUCT SUMMARY

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D^3
24V	5m Ω	51A

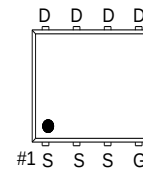


Features

- Pb-Free, Halogen Free and RoHS compliant.
- Low $R_{DS(on)}$ to Minimize Conduction Losses.
- Ohmic Region Good $R_{DS(on)}$ Ratio.
- Optimized Gate Charge to Minimize Switching Losses.
- Products Integrated ESD diode with ESD Protected.

Applications

- Protection Circuits Applications.
- Logic/Load Switch Circuits Applications.



G : GATE
D : DRAIN
S : SOURCE

100% UIS Tested
100% Rg Tested

ABSOLUTE MAXIMUM RATINGS ($T_A = 25\text{ }^\circ\text{C}$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		V_{DS}	24	V
Gate-Source Voltage		V_{GS}	± 12	V
Continuous Drain Current ³	$T_C = 25\text{ }^\circ\text{C}$	I_D	51	A
	$T_C = 100\text{ }^\circ\text{C}$		32	
	$T_A = 25\text{ }^\circ\text{C}$		18.6	
	$T_A = 70\text{ }^\circ\text{C}$		15	
Pulsed Drain Current ¹		I_{DM}	120	
Avalanche Current		I_{AS}	30	
Avalanche Energy	$L = 0.1\text{mH}$	E_{AS}	45	mJ
Power Dissipation ⁴	$T_C = 25\text{ }^\circ\text{C}$	P_D	24	W
	$T_C = 100\text{ }^\circ\text{C}$		9.6	
	$T_A = 25\text{ }^\circ\text{C}$		3.1	
	$T_A = 70\text{ }^\circ\text{C}$		2	
Operating Junction & Storage Temperature Range		T_j, T_{stg}	-55 to 150	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE		SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Ambient ²	$t \leq 10s$	$R_{\theta JA}$		40	°C / W
Junction-to-Ambient ²	Steady-State	$R_{\theta JA}$		70	
Junction-to-Case	Steady-State	$R_{\theta JC}$		5.2	

¹Pulse width limited by maximum junction temperature.²The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.³Package limitation current is 36A⁴The Power dissipation is based on $R_{\theta JA}$ $t \leq 10s$ value.ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	24			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.7	0.8	1.3	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 10V$			± 30	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$			1	μA
		$V_{DS} = 20V, V_{GS} = 0V, T_J = 55\text{ }^{\circ}C$			10	
Drain-Source On-State Resistance ¹	$R_{DS(ON)}$	$V_{GS} = 2.5V, I_D = 10A$		5.2	8.5	$m\Omega$
		$V_{GS} = 4.5V, I_D = 10A$		3.7	5.5	
		$V_{GS} = 10V, I_D = 15A$		3.1	5	
Forward Transconductance ¹	g_{fs}	$V_{DS} = 5V, I_D = 15A$		66		S
DYNAMIC						
Input Capacitance	C_{iss}	$V_{GS} = 0V, V_{DS} = 12V, f = 1MHz$		1803		pF
Output Capacitance	C_{oss}			294		
Reverse Transfer Capacitance	C_{rss}			225		
Gate Resistance	R_g	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$		1.9		Ω
Total Gate Charge ²	$Q_{g(VGS=10V)}$	$V_{DS} = 12V, I_D = 15A$		41		nC
	$Q_{g(VGS=4.5V)}$			20		
Gate-Source Charge ²	Q_{gs}			2		
Gate-Drain Charge ²	Q_{gd}			6.7		
Turn-On Delay Time ²	$t_{d(on)}$	$V_{DD} = 12V$ $I_D \cong 15A, V_{GEN} = 10V, R_G = 6\Omega$		13		nS
Rise Time ²	t_r			89		
Turn-Off Delay Time ²	$t_{d(off)}$			77		
Fall Time ²	t_f			136		

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (T_J = 25 °C)

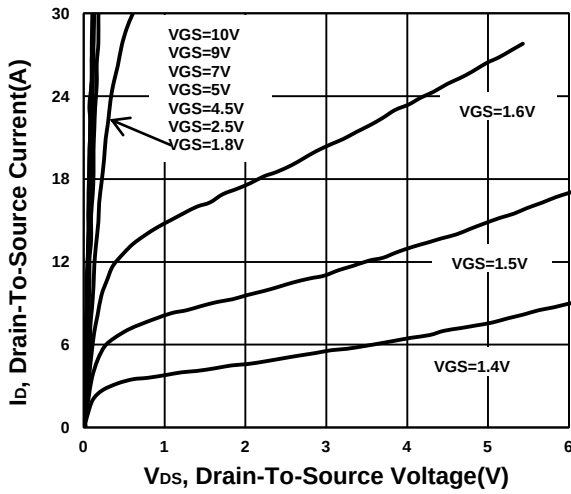
Continuous Current ³	I _S			20	A
Forward Voltage ¹	V _{SD}	I _F = 15A, V _{GS} = 0V		1.2	V
Reverse Recovery Time	t _{rr}	I _F = 15A , dI _F /dt = 100A / μS		22	nS
Reverse Recovery Charge	Q _{rr}			7.7	nC

¹Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.

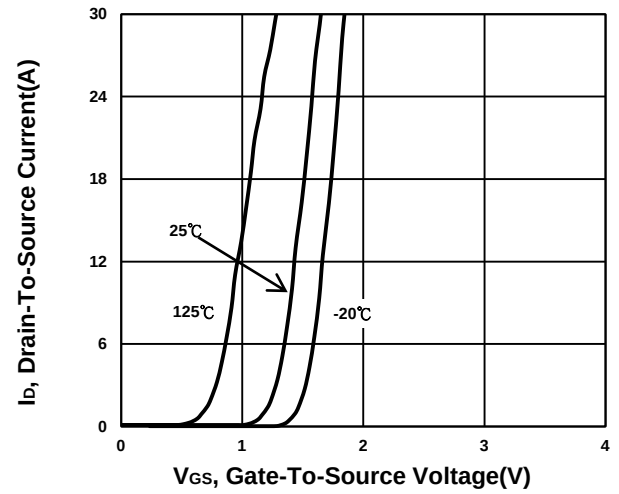
²Independent of operating temperature.

³Package limitation current is 36A

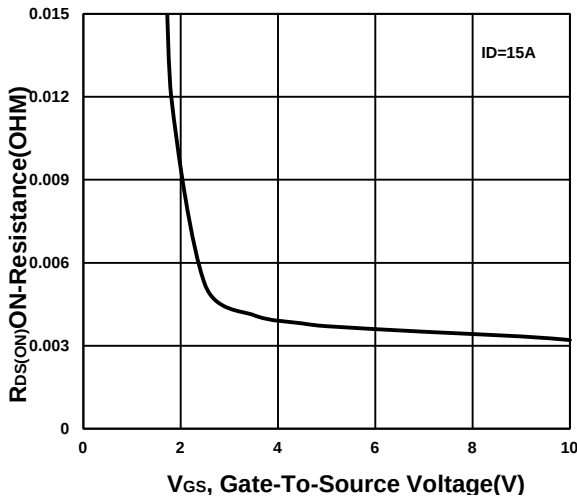
Output Characteristics



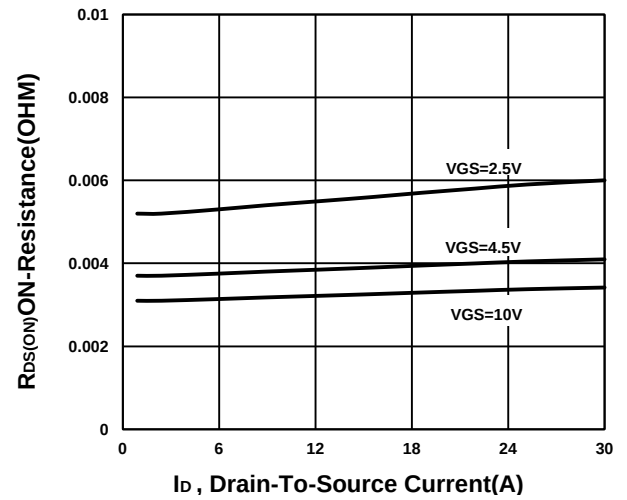
Transfer Characteristics



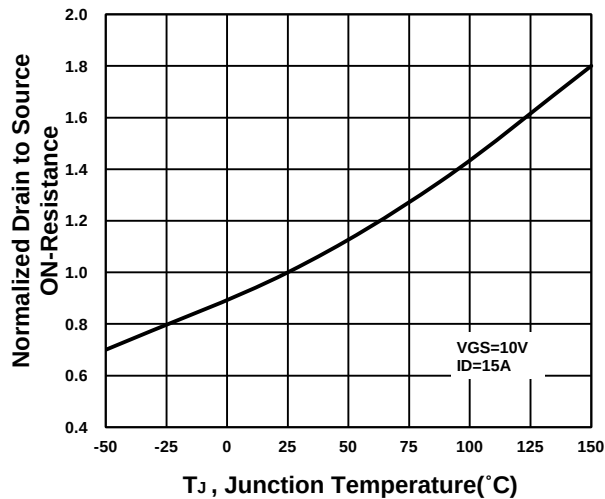
On-Resistance VS Gate-To-Source



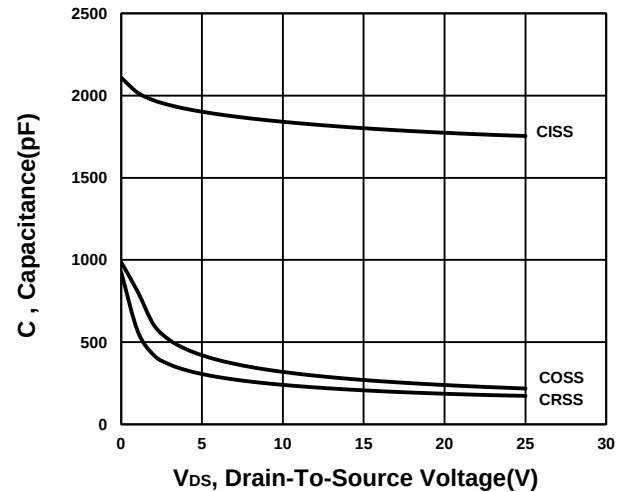
On-Resistance VS Drain Current



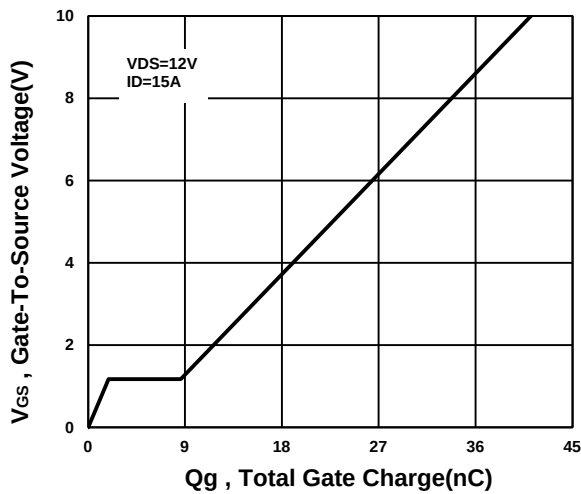
On-Resistance VS Temperature



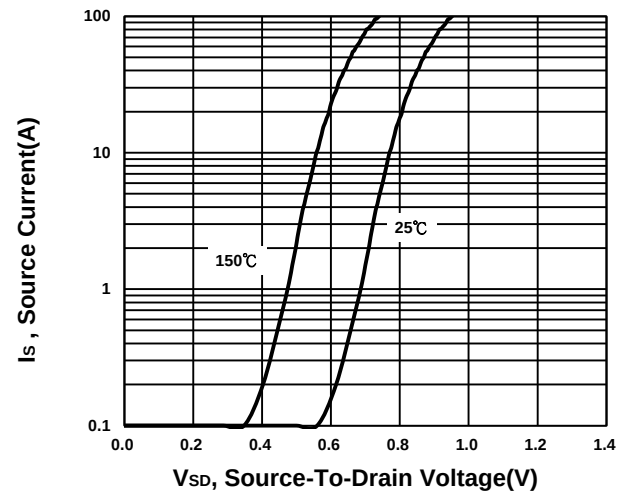
Capacitance Characteristic



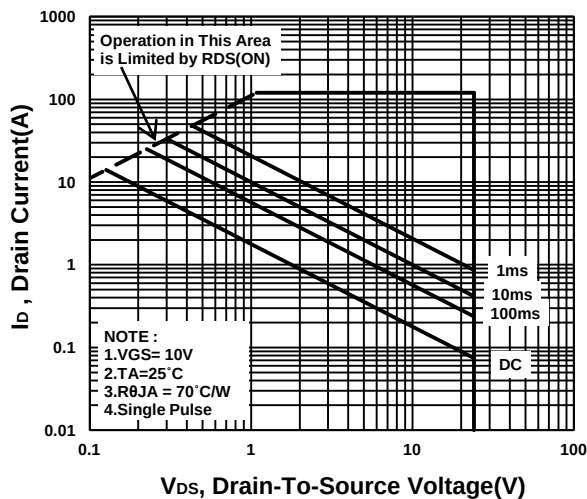
Gate charge Characteristics



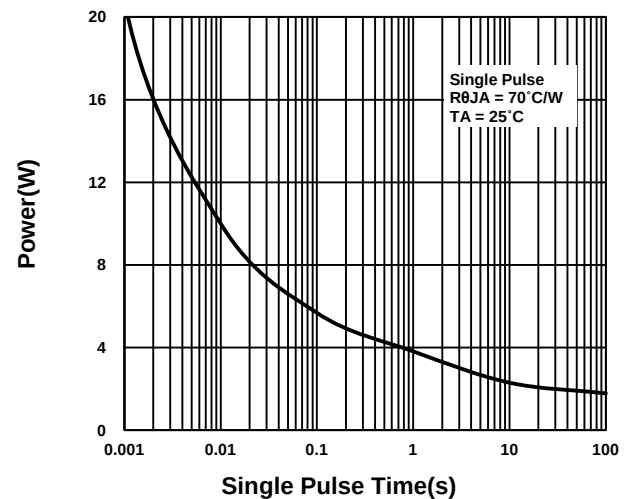
Source-Drain Diode Forward Voltage



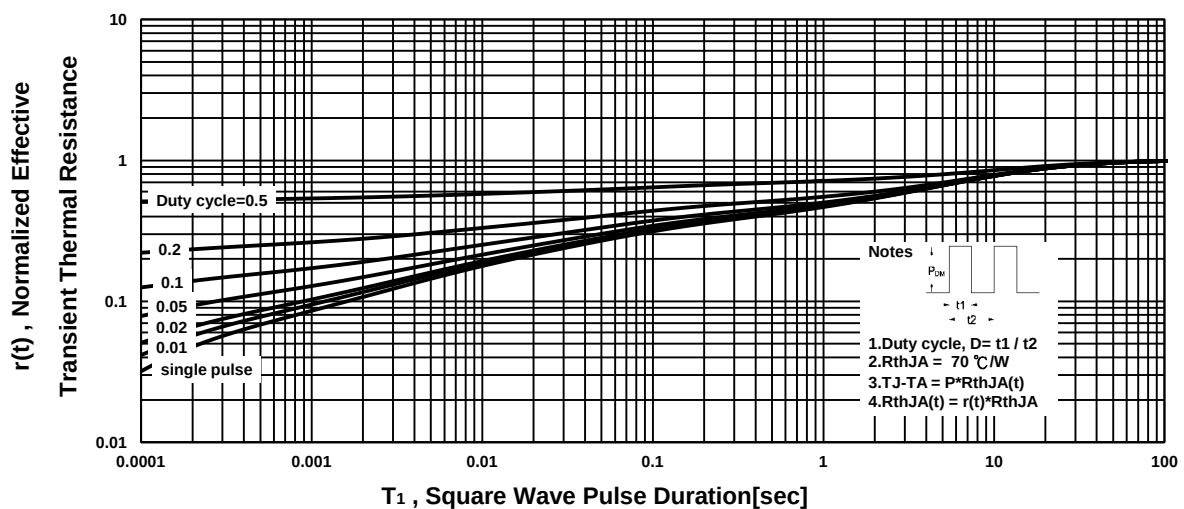
Safe Operating Area



Single Pulse Maximum Power Dissipation



Transient Thermal Response Curve



Transient Thermal Response Curve

